RT9519E

Buy

Sample &

Linear Single Cell Li-Ion Battery Charger with Auto Power Path Management

Technical

Documentation

General Description

The RT9519E is an integrated single-cell Li-ion battery charger with auto power path management (APPM). No external MOSFETs are required. The RT9519E enters sleep mode when power is removed. Charging tasks are optimized by using a control algorithm to vary the charge rate, including pre-charge mode, fast charge mode and constant voltage mode. For the RT9519E, the charge current can also be programmed with an external resistor and modified with an external GPIO. The scope that the battery regulation voltage can be modified with an external GPIO depends on the battery temperature. The internal thermal feedback circuitry regulates the die temperature to optimize the charge rate for all ambient temperatures. The charging task will always be terminated in constant voltage mode when the charging current reduces to the termination current of 10% x ICHG_FAST. Other features include under voltage protection and over voltage protection for VIN supply.

The recommended junction temperature range spans from -40° C to 125° C, while the ambient temperature range extends from -40° C to 85° C.

Ordering Information

RT9519E

Lead Plating System G : Richtek Green Policy Compliant

Note:

Richtek products are Richtek Green Policy compliant and compatible with the current requirements of IPC/JEDEC J-STD-020.

Marking Information



67= : Product Code YMDNN : Date Code

Features

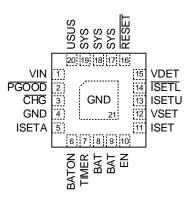
- 28V Maximum Rating for VIN Power
- Selectable Power Current Limit (0.1A / 0.5A / 1.5A)
- Integrated Power MOSFETs
- Auto Power Path Management (APPM)
- Battery Charging Current Control
- Battery Regulation Voltage Control
- Voltage Detector by VDET and RESET Pin
- Programmable Charging Current and Safe Charge Timer
- Under Voltage Protection, Over Voltage
 Protection
- Power Good and Charge Status Indicator
- Optimized Charge Rate via Thermal Feedback
- Thin 20-Lead WQFN Package
- RoHS Compliant and Halogen Free

Applications

- Digital Cameras
- PDAs and Smart Phones
- Portable Instruments

Pin Configuration

(TOP VIEW)



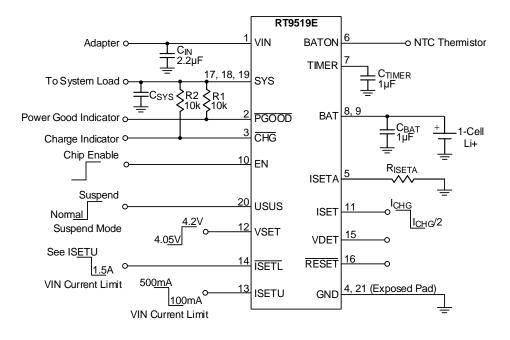
WQFN-20L 3x3

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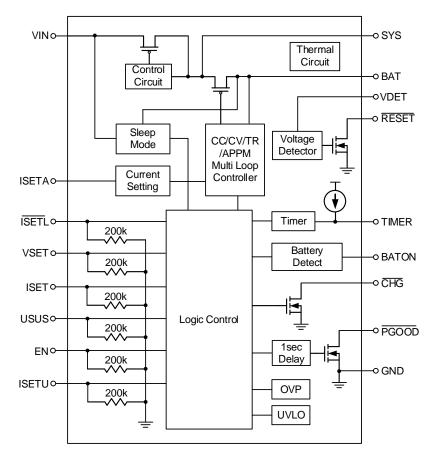
DS9519E-03 February 2024



Typical Application Circuit



Functional Block Diagram



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www.richtek.com		DS9519E-03	February	2024

Functional Pin Description

Pin No.	Pin Name	Pin Function
1	VIN	Supply voltage input.
2	PGOOD	Power good status output. Active low, open-drain output.
3	CHG	Charger status output. Active low, open-drain output.
4, 21 (Exposed Pad)	GND	Ground. The exposed pad must be soldered to a large PCB and connected to GND for maximum power dissipation.
5	ISETA	Charge current set input. Connect a resistor (RISETA) between ISETA and GND. ICHG_FAST = (VISETA / RISETA) x 300. ICHG_PRE = 10% x ICHG_FAST.
6	BATON	Battery detector pin. Detect the presence of battery. Connect BATON to the NTC thermistor. If battery is not presence, charge function disables.
7	TIMER	Safe charge timer setting.
8, 9	BAT	Battery charge current output.
10	EN	Charge enable. Active high input. 200k Ω pull low.
11	ISET	Half charge current set input. Control by external GPIO, L = ICHG1/2, H = ICHG1, 200k Ω pull low.
12	VSET	VBAT set input. Control by external GPIO. L = 4.05V, H = 4.2V, 200k Ω pull low.
13	ISETU	VIN current limit control input. When $\overline{\text{ISETL}}$ = H, L = 100mA, H = 500mA, 200k Ω pull low.
14	ISETL	VIN current limit control input. H : see ISETU, L = 1.5A, 200k Ω pull low.
15	VDET	Voltage detection input.
16	RESET	Open-drain output. $\overline{\text{RESET}}$ = High Z, when VDET >1V.
17, 18, 19	SYS	System connect pin. Connect this pin to system with a minimum $10\mu F$ ceramic capacitor connected to GND.
20	USUS	VIN suspend control input. H = Suspend, L = No suspend. 200k Ω pull low.



Absolute Maximum Ratings (Note 1)

Supply Input Voltage, VIN	0.3V to 28V
• CHG, PGOOD, RESET	0.3V to 28V
Other Pins	0.3V to 6V
BAT Continuous Current (Total in Two Pins) (Note 2)	2.5A
 Power Dissipation, PD @ TA = 25°C 	
WQFN-20L 3x3	1.471W
Package Thermal Resistance (Note 3)	
WQFN-20L 3x3, θJA	68°C/W
WQFN-20L 3x3, θJC	7.5°C/W
Lead Temperature (Soldering, 10sec.)	260°C
Junction Temperature	150°C
Storage Temperature Range	–65°C to 150°C
ESD Susceptibility (Note 4)	
HBM (Human Body Model)	2kV
MM (Machine Model)	200V

Recommended Operating Conditions (Note 5)

 Supply Input Voltage Range, VIN (ISETL = L) 	- 4.35V to 6V
Supply Input Voltage Range, VIN (ISETL = H)	- 4.4V to 6V
Ambient Temperature Range	- –40°C to 85°C
Junction Temperature Range	- –40°C to 125°C

Electrical Characteristics

(V_{IN} = 5V, V_{BAT} = 4V, T_A = 25°C, unless otherwise specified)

Parameter	Parameter Symbol Test Conditions		Min	Тур	Мах	Unit
Supply Input						
VIN Under Voltage Lockout Threshold	Vuvlo	VIN = 0V to 4V	3.1	3.3	3.5	V
VIN Under Voltage Lockout Hysteresis	ΔΫυνίο	$V_{IN} = 4V \text{ to } 0V$		240		mV
VIN Supply Current	ISUPPLY	ISYS = IBAT = 0mA, EN = H (VBAT > VREGx)		1	2	mA
		ISYS = IBAT = 0mA, EN = L (VBAT > VREGx)		0.8	1.5	mA
VIN Suspend Current	lusus	VIN = 5V, USUS = H		195	333	μA
VBAT Sleep Leakage Current	ISLEEP	VBAT > VIN (VIN = 0V)		5	15	μA
VIN-BAT VOS Rising	Vos_H			100	200	mV
VIN-BAT VOS Falling	Vos_L		10	50		mV
Voltage Regulation	L	•	•	•	•	

RT9519E

ParameterSymbolTest ConditionsMinTypMaxUnitBattery Regulation Voltage Accuracy1VREG1Loading = 20mA When VSET = H4.164.24.23VBattery Regulation Voltage Accuracy2VREG2Loading = 20mA When VSET = L4.014.054.08VSystem Regulation Voltage Accuracy2VSYSIsys = 800mA5.35.55.7VAPPM Regulation Voltage VSYSVSYSISETL = H4.224.334.4VMin to VSYS MOSFET Or- ResistanceRDS(ON)Ivin = 1000mA0.220.35ΩBAT to VSYS MOSFET Or- ResistanceRDS(ON)VBAT = 4.2V, ISYS = 1A0.050.1ΩRe-Charge ThresholdAVRECHGBattery Regulation - Recharge level60100140mVCurrent RegulationVISETAVISETAVBAT = 4V, RISETA = 1KΩ70600630mAVIN Charge Setting RangIcHGVBAT = 4V, RISETA = 1KΩ570600630mAVIN Charge Current Accuracy2IcHG2VBAT = 4V, RISETA = 1KΩ570600630mAVIN Charge Current Accuracy2IcHG2VBAT = 4V, RISETA = 1KΩ570600mAVIN Charge Current Accuracy2IcHG2VBAT = 4V, RISETA = 1KΩ570600mAVIN Charge Current Accuracy2IcHG2VBAT = 4V, RISETA = 1KΩ570600mAVIN Charge Current Accuracy2IcHG2VBAT = 4V, RISETA = 1KΩ570								
Accuracy1 VHEC1 When VSET = H 4.16 4.2 4.23 V Battery Regulation Voltage Accuracy2 VREG2 Loading = 20mA When VSET = L 4.01 4.05 4.08 V System Regulation Voltage VSYS ISYS = 800mA 5.3 5.5 5.7 V APPM Regulation Voltage VAPPM ISET = H 4.2 4.3 4.4 V VIN to VSYS MOSFET On- Resistance RDS(ON) ININ = 1000mA 0.22 0.35 Ω Re-Charge Threshold AVREGCHG Battery Regulation - Recharge level 60 100 140 mV VIN to VSYS MOSFET On- Resistance RDS(ON) VBAT = 4.2V, ISYS = 1A 0.05 0.1 Ω Re-Charge Threshold AVREGCHG Battery Regulation - Recharge level 60 100 1-4 0 VIN Charge Setting Range ICHG VBAT = 3.8V, RISETA = 1KΩ 1200 mA VIN Charge Current Accuracy2 ICHG2 VBAT = 3.8V, RISETA = 1KΩ 285 300 315 mA	Parameter		Symbol	Test Conditions	Min	Тур	Max	Unit
$\begin{array}{c c c c c c c c c c c c c c c c c c c $, ,	age	VREG1		4.16	4.2	4.23	V
$\begin{array}{c c c c c c c c c c c c c c c c c c c $		age	Vreg2		4.01	4.05	4.08	V
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	System Regulation Vol	tage	Vsys	ISYS = 800mA	5.3	5.5	5.7	V
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	APPM Regulation Volta	ige	Vappm		3.85	3.95	4.05	V
Resistance RDS(ON) IVIN = 1000mA 0.2 0.35 Ω BAT to VSYS MOSFET On-Resistance RDS(ON) VBAT = 4.2V, IsVS = 1A 0.05 0.1 Ω Re-Charge Threshold Λ VREGCHG Battery Regulation - Recharge level 60 100 140 mV Current Regulation ISETA Set Voltage (Fast Charge VISETA VBAT = 4V, RISETA = 1K Ω 2 V VIN Charge Setting Range ICHG VBAT = 4V, RISETA = 1K Ω 570 600 630 mA VIN Charge Current Accuracy1 ICHG2 VBAT = 3.8V, RISETA = 1K Ω 285 300 315 mA VIN Charge Current Accuracy2 ICHG2 VBAT = 3.8V, RISETA = 1K Ω 285 300 315 mA VIN Current Limit IVIN ISET = L 1.5A Mode) 1 1.5 1.8 A VIN Current Limit IVIN ISET = H, ISETU = H 430 475 500 mA VIN Current Limit IVIN ISET = N, ISETU = H, ISETU = L <t< td=""><td>DPM Regulation Voltag</td><td>le</td><td>Vdpm</td><td>ISETL = H</td><td>4.2</td><td>4.3</td><td>4.4</td><td>V</td></t<>	DPM Regulation Voltag	le	Vdpm	ISETL = H	4.2	4.3	4.4	V
Resistance MDS(ON) VBAT = 4.2V, ISVS = 1A 0.05 0.1 Ω Re-Charge Threshold ΔV REGCHG Battery Regulation - Recharge level 60 100 140 mV Current Regulation - Recharge Ivel 60 100 140 mV Current Regulation - Recharge Ivel 60 100 1200 mA VIN Charge Setting Range ICHG VBAT = 4V, RISETA = 1KΩ 570 600 630 mA VIN Charge Current Accuracy1 ICHG1 VBAT = 3.8V, RISETA = 1KΩ 285 300 315 mA VIN Charge Current Accuracy2 ICHG2 VBAT = 4.V, RISETA = 1KΩ 285 300 315 mA VIN Charge Current Accuracy2 ICHG2 VBAT = 3.8V, RISETA = 1KΩ 285 300 315 mA VIN Current Limit IVIN ISET = L (1.5A Mode) 1 1.5 1.8 A VIN Current Limit IVIN ISET = H, ISETU = H 430 475 500 mA GiSOD		On-	Rds(on)	I∨IN = 1000mA		0.2	0.35	Ω
Re-Charge Intestion ΔVRECH of Recharge level Recharge level 60 100 140 INV Current Regulation ISETA Set Voltage (Fast Charge phase) VISETA VBAT = 4V, RISETA = 1kΩ 2 V VIN Charge Setting Range ICHG VBAT = 4V, RISETA = 1kΩ 2 V VIN Charge Current Accuracy1 ICHG VBAT = 4V, RISETA = 1kΩ 570 600 630 mA VIN Charge Current Accuracy2 ICHG2 VBAT = 3.8V, RISETA = 1kΩ 285 300 315 mA VIN Charge Current Accuracy2 ICHG2 VBAT = 1.1, ISETU = 1.4 430 475 500 mA VIN Current Limit ISETL = H, ISETU = L 1.5 1.8 A VIN Current Limit VPRECH BAT Falling 2.7 2.8 2.9 V BAT Pre-Charge Threshold VPRECH BAT Falling 2.7 2.8 2.9 V BAT Pre-Charge Threshold VPRECH BAT Falling 2.7 2.8 2.9 V		On-	Rds(on)	VBAT = 4.2V, ISYS = 1A		0.05	0.1	Ω
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Re-Charge Threshold		ΔV REGCHG		60	100	140	mV
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Current Regulation		-	-	-		1	
VIN Charge Current Accuracy1ICHG1VBAT = 4V, RISETA = 1K\Omega ISET = H570600630mAVIN Charge Current Accuracy2ICHG2VBAT = 3.8V, RISETA = 1K\Omega ISET = L285300315mAVIN Charge Current Accuracy2ICHG2VBAT = 3.8V, RISETA = 1K\Omega ISET = L285300315mAVIN Current LimitISET = L(1.5A Mode)11.51.8AVIN Current LimitISET = L(1.5A Mode)11.51.8AISET = L(1.5A Mode)11.51.8AISET = L(1.5A Mode)11.51.8AVIN Current LimitISET = H, ISETU = H (500M A Mode)475500mAPre-ChargeBAT Pre-Charge ThresholdVPRECHBAT Falling2.72.82.9VBAT Pre-Charge ThresholdVPRECHBAT Falling2.72.82.9VPre-Charge CurrentICHG_PREVBAT = 2V51015%Charge Current Ratio to Fast Charge (Except USB100 Mode)ITERMISETI = H, ISETU = H ISETI = L, ISETU = L ISETI = L, ISETU = L51015%Colspan="4">IFERM2ISETI = H, ISETU = L ISETI = L, ISETU = L-3.3%Login Input/OutputVERGEICHG = 5mA200mVRESET	• •	st Charge	VISETA	VBAT = 4V, RISETA = $1k\Omega$		2		V
VIN Charge Current Accuracy1 ICHG1 ISET = H S70 600 630 IMA VIN Charge Current Accuracy2 ICHG2 VBAT = 3.8V, RISETA = 1KΩ ISET = L 285 300 315 mA VIN Current Limit ISET = L (1.5A Mode) 1 1.5 1.8 A VIN Current Limit ISET = L (1.5A Mode) 1 1.5 1.8 A VIN Current Limit ISET = H, ISETU = L (1.5A Mode) 1 1.5 1.8 A VIN Current Limit ISET = H, ISETU = L (1.5A Mode) 1 1.5 1.8 A VIN Current Limit ISET H, ISETU = H, ISETU = H 430 475 500 mA Pre-Charge ISETL = H, ISETU = L 70 90 100 mA Pre-Charge Threshold VPRECH BAT Falling 2.7 2.8 2.9 V BAT Pre-Charge Current $\$ ICHG_PRE VBAT = 2.V 5 10 15 % Charge Termination Current Ratio to Fast Charge (ISB100 Mode) ITERM2 </td <td>VIN Charge Setting Ra</td> <td>nge</td> <td>Існд</td> <td></td> <td>100</td> <td></td> <td>1200</td> <td>mA</td>	VIN Charge Setting Ra	nge	Існд		100		1200	mA
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VIN Current LimitIntermeter (100 mmode)(100 mmode)VIN $uit [SETL = H, ISETU = H, (SOMA Mode)430475500mAPre-ChargeBAT Pre-Charge ThresholdVPRECHBAT Falling2.72.82.9VBAT Pre-Charge CurrentAVPRECHBAT Falling2.72.82.9VPre-Charge CurrentICHG_PREVBAT = 2V51015%Pre-Charge Current Ratio to FastCharge (USB100 Mode)ITERM2ISETL = H, ISETU = L3.3%CHG$	VIN Charge Current Ac	curacy2	ICHG2		285	300	315	mA
VIN Current LimitIVINISET (500mA Mode)430470500111A(500mA Mode)47090100mAPre-ChargeBAT Pre-Charge ThresholdVPRECHBAT Falling2.72.82.9VBAT Pre-Charge ThresholdVPRECHBAT Falling2.72.82.9VBAT Pre-Charge ThresholdVPRECHBAT Falling2.72.82.9VBAT Pre-Charge ThresholdVPRECHBAT Falling2.72.82.9VPre-Charge CurrentICHG_PREVBAT = 2V51015%Charge Termination DetectionTermination Current Ratio to Fast Charge (Except USB100 Mode)ITERM2ISETL = H, ISETU = H ISETL = L, ISETU = X51015%CHG IITERM2ISETL = H, ISETU = L ISETL = L, ISETU = L3.3%Login Input/OutputCHG Pull Down VoltageVCHGICHG = 5mA200mVPGOOD Pull Down VoltageVPGOODIPGOOD = 5mA200mVRESET Pull Down VoltageVRESETIRESET = 5mA200mVEN, ISETL, USUS, ISETU, VSET, ISETLogic-HighVIH1.5v				ISETL = L (1.5A Mode)	1	1.5	1.8	А
Pre-Charge7090100111ABAT Pre-Charge ThresholdVPRECHBAT Falling2.72.82.9VBAT Pre-Charge Threshold Δ VPRECHBAT Falling2.72.82.9VBAT Pre-Charge Threshold Δ VPRECHBAT Falling200mVPre-Charge CurrentICHG_PREVBAT = 2V51015%Charge Termination DetectionTermination Current Ratio to Fast Charge (Except USB100 Mode)ITERMISETL = H, ISETU = H ISETL = L, ISETU = X51015%Termination Current Ratio to Fast Charge (USB100 Mode)ITERM2ISETL = H, ISETU = L ISETL = L, ISETU = X51015%Cogio Input/OutputCHG Pull Down VoltageVCHGICHG = 5mA200mVPGOOD Pull Down VoltageVRESETIRESET = 5mA200mVRESET Pull Down VoltageVRESETIRESET = 5mA200mVEN, ISETL, USUS, ISETU, VSET, ISETLogic-HighViHInc.1.57	VIN Current Limit		Ivin	-	430	475	500	mA
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Hysteresis $\Delta VPRECH$ 200 INVPre-Charge CurrentICHG_PREVBAT = 2V51015%Charge Termination DetectionTermination Current Ratio to Fast Charge (Except USB100 Mode)ITERM $ISETL = H, ISETU = H$ ISETL = L, ISETU = X51015%Termination Current Ratio to Fast Charge (USB100 Mode)ITERM2 $ISETL = H, ISETU = L$ ISETL = H, ISETU = L3.3%Login Input/OutputCHG Pull Down VoltageVCHGICHG = 5mA200mVPGOOD Pull Down VoltageVPGOODIPGOOD = 5mA200mVRESET Pull Down VoltageVRESETIRESET = 5mA200mVEN, ISETL, USUS, ISETU, VSET, ISETLogic-HighVIH1.5 V	BAT Pre-Charge Thres	hold	VPRECH	BAT Falling	2.7	2.8	2.9	V
$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$	-	hold	∆Vprech			200		mV
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Pre-Charge Current		ICHG_PRE	VBAT = 2V	5	10	15	%
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	Charge Termination D	etection						
$\begin{array}{c c c c c c c c c c c c c c c c c c c $			ITERM		5	10	15	%
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			ITERM2	ISETL = H, ISETU = L		3.3		%
PGOOD Pull Down VoltageVPGOODIPGOOD = 5mA200mVRESET Pull Down VoltageVRESETIRESET = 5mA200mVEN, ISETL, USUS, ISETU, VSET, ISETLogic-HighVIH1.5V	Login Input/Output		•			·	•	
RESET Pull Down Voltage VRESET IRESET = 5mA 200 mV EN, ISETL, USUS, ISETU, VSET, ISET Logic-High VIH 1.5 V	CHG Pull Down Voltage	е	VCHG	ICHG = 5mA		200		mV
EN, ISETL, USUS, Logic-High VIH 1.5 V	PGOOD Pull Down Voltage		VPGOOD	IPGOOD = 5mA		200		mV
ISETU, VSET, ISET	RESET Pull Down Volt	age	VRESET	IRESET = 5mA		200		mV
		Logic-High	VIH		1.5			1/
		Logic-Low	VIL				0.4	v

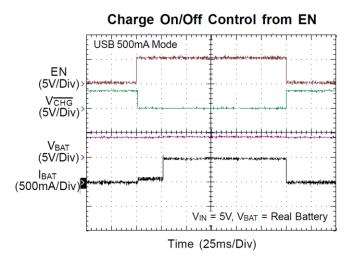
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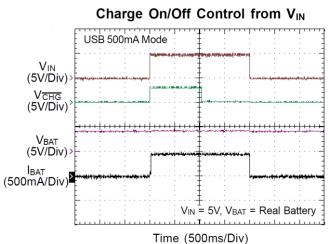
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Protection						
Thermal Regulation	T _{REG}			125		°C
Thermal Shutdown Temperature	TSD			155		°C
Thermal Shutdown Hysteresis	ΔTSD			20		°C
Over Voltage Protection	Vovp	VIN Rising	6.25	6.5	6.75	V
Over Voltage Protection Hysteresis	ΔVovp	$V_{IN} = 7V \text{ to } 5V,$ $V_{OVP} - \Delta V_{OVP}$		100		mV
VDET	Vdet	VDET Falling	0.98	1	1.02	V
BATON	VBATON	BATON Rising	2.8	2.9	3	V
Output Short Circuit Detection Threshold	VSHORT	Vbat-Vsys		300		mV
Time						
Pre-Charge Fault Time	t PCHG	CTIMER = $1\mu F$ (1/8 x tFCHG)	1440	1800	2160	S
Fast Charge Fault Time	tFCHG	CTIMER = 1µF	11520	14400	17280	S
PGOOD Deglitch Time		Time measured from VIN : $0 \rightarrow 5V$ 1µs rise time to $\overrightarrow{PGOOD} = L$		1	-	s
Input Over Voltage Blanking Time	tovp			50		μS
Pre-Charge to Fast-Charge Deglitch Time	tPF			25		ms
Fast-Charge to Pre-Charge Deglitch Time	tFP			25		ms
Termination Deglitch Time	t TERMI			25		ms
Recharge Deglitch Time	trechg			100		ms
Input Power Loss to SYS LDO Turn-Off Delay Time	tno_in			25		ms
Short Circuit ,Deglitch Time	tSHORT			250		μS
Short Circuit Recovery Time	tSHORT-R			64		ms

- **Note 1**. Stresses beyond those listed under "Absolute Maximum Ratings" June cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions June affect device reliability.
- Note 2. Guaranteed by design.
- **Note 3**. θJA is measured under natural convection (still air) at TA = 25°C with the component mounted on a high effective-thermalconductivity four-layer test board on a JEDEC 51-7 thermal measurement standard. θJC is measured at the exposed pad of the package.
- Note 4. Devices are ESD sensitive. Handling precautions are recommended.
- Note 5. The device is not guaranteed to function outside its operating conditions.

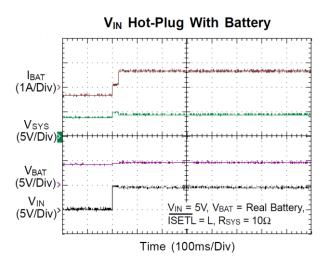
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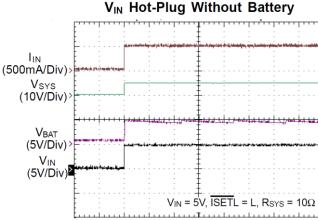
Typical Operating Characteristics



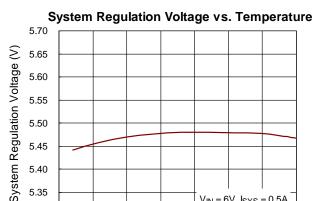


V_{IN} Removal IBAT (2A/Div) Vsys (5V/Div) VBAT (5V/Div) V_{IN} (5V/Div)≯ VIN = 5V, VBAT = Real Batter $\overline{\text{ISETL}} = L, R_{\text{SYS}} = 10\Omega$ цĿ Time (10ms/Div)









Temperature (°C)

50

25

5.30

-50

-25

0

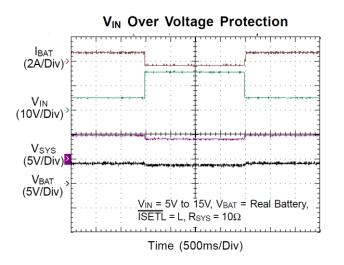
 $V_{IN} = 6V, I_{SYS} = 0.5A$

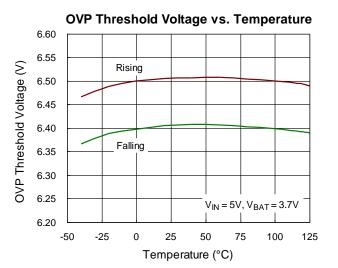
100

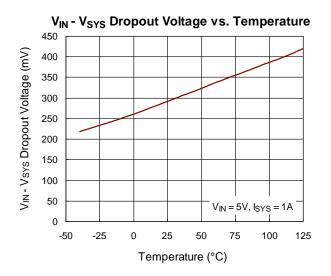
125

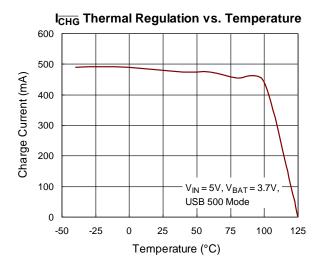
75



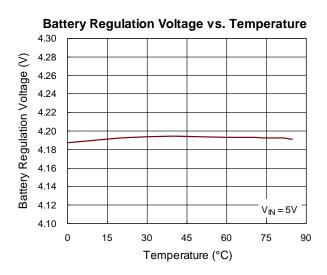






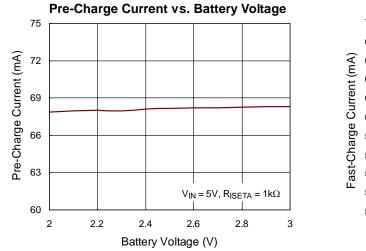


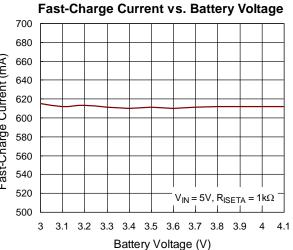
VBAT - VSYS Dropout Voltage vs. Temperature 120 VBAT - VSYS Dropout Voltage (mV) 100 80 60 40 20 $V_{BAT} = 4.2V, I_{SYS} = 1A$ 0 -50 -25 0 25 50 75 100 125 Temperature (°C)



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Application Information

Richtek's component specification does not include the following information in the Application Information section. Thereby no warranty is given regarding its validity and accuracy. Customers should take responsibility to verify their own designs and reserve suitable design margin to ensure the functional suitability of their components and systems.

The RT9519E is a fully integrated single-cell Li-ion battery charger ideal for portable applications. The internal thermal feedback circuitry regulates the die temperature to optimize the charge rate for all ambient temperatures. Other features include under voltage protection and over voltage protection.

Pre-charge Mode

When the output voltage is lower than 2.8V, the charging current will be reduced to a fast-charge current ratio set by RISETA to protect the battery life time.

Fast-charge Mode

When the output voltage is higher than 3V, the charging current will be equal to the fast-charge current set by RISETA.

Constant-Voltage Mode

When the output voltage is near 4.2V, and the charging current fall below the termination current, after a deglitch time check of 25ms, the charger will become disabled and CHG will go from L to H.

Re-charge Mode

When the chip is in charge termination mode, the charging current will gradually go down to zero. However, once the voltage of the battery drops to below 4.1V, there will be a deglitch time of 100ms and then the charging current will resume again.

Charging Current Decision

The charge current can be set according to the following equations :

$$I_{CHG_FAST} = \frac{V_{ISETA}}{R_{ISETA}} \times 300$$

If ISET = L (for ICHG2)

$$I_{CHG_FAST} = \frac{V_{ISETA}}{R_{ISETA}} \times 150$$

ICHG_PRE = 10% x ICHG_FAST

Time Fault

During the fast charge phase, several events may increase the charging time.

For example the system load current may have activated the APPM loop which reduces the available charging current, the device has entered thermal regulation because the IC junction temperature has exceeded TREG. During each of these events, if 3V < VBAT < 4.1V, the internal charging time is slowed down proportionately to the reduction in charging current. However, once the duration exceeds the fault time, the CHG output will flash at approximately 2Hz to indicate a fault condition and the charge current will be reduced to about 1mA.

$$t_{FCHG_true} = t_{FCHG} \times \frac{2V}{V_{ISETA}}$$

tFCHG true : modified timer in fast tFCHG : original timer in fast charger

$$t_{FCHG} = 14400 \times \left(\frac{C_{TIMER}}{1\mu F}\right)$$

$$t_{PCHG} = \frac{t_{FCHG}}{8}$$

tPCHG : timer in pre-charge

Time fault release methods :

- (1) Re-plug power
- (2) Toggle EN
- (3) Enter/exit suspend mode
- (4) Remove Battery

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(5) OVP

Note that the fast charge fault time is independent of the charge current.

Power Good

VIN Power Good (PGOOD = L)

Input State	PGOOD Output
VIN < VUVLO	High Impedance
VUVLO < VIN < VBAT + VOS_H	High Impedance
VBAT + VOS_H < VIN < VOVP	Low Impedance
VIN > VOVP	High Impedance

Charge State Indicator

Charge State	CHG Output
Charging	Low(for first charge
Charging Suspended by Thermal Loop	cycle)
Safety Timers Expired	2Hz Flash
Charging Done	
Recharging after Termination	High Impedance
IC Disabled or no Valid Input Power	

Charge Enable

When EN is High, the charger turns on. When EN is low, the charger turns off. EN is pulled low at the initial condition.

VIN Input Current Limit

ISETL	ISETU	VIN Input Current Limit
Н	L	90mA
Н	Н	475mA
L	Х	1.5A

Suspend Mode

Set USUS = H, and the charge will enter Suspend Mode. In the Suspend Mode, CHG is in high impedance and $IUSUS(MAX) < 333 \mu A.$

Power Switch

For the RT9519E, there are three power scenarios :

(1) When a battery and an external power supply (USB

or adapter) are connected simultaneously :

If the system load requirements exceed that of the input current limit, the battery will be used to supplement the current to the load. However, if the system load

requirements are less than that of the input current limit, the excess power from the external power supply will be used to charge the battery.

- (2) When only the battery is connected to the system : The battery provides the power to the system.
- (3) When only an external power supply is connected to the system :

The external power supply provides the power to the system.

Input DPM Mode

For the RT9519E, the input voltage is monitored when the USB100 or USB500 is selected. If the input voltage is lower than V_{DPM}, the input current limit will be reduced to stop the input voltage from dropping any further. This can prevent the IC from damaging improperly configured or inadequately designed USB sources.

APPM Mode

Once the sum of the charging and system load currents becomes higher than the maximum input current limit, the SYS pin voltage will be reduced. When the SYS pin voltage is reduced to VAPPM, the RT9519E will automatically operate in APPM mode. In this mode, the charging current is reduced while the SYS current is increased to maintain system output. In APPM mode, the battery termination function is disabled.

Battery Supplement Mode Short Circuit Protect

In APPM mode, the SYS voltage will continue to drop if the charge current is zero and the system load increases beyond the input current limit. When the SYS voltage decreases below the battery voltage, the battery will kick in to supplement the system load until the SYS voltage rises above the battery voltage.

While in supplement mode, there is no battery supplement current regulation. However, a built in short circuit protection feature is available to prevent any abnormal current situations. While the battery is supplementing the load, if the difference between the

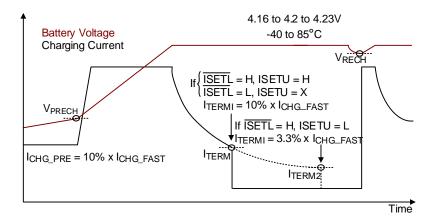
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battery and SYS voltage becomes more than the short circuit threshold voltage, SYS will be disabled. After a short circuit recovery time, t_{SHORT_R} , the counter will be restarted. In supplement mode, the battery termination function is disabled. Note that for the battery supply mode exit condition, $V_{BAT} - V_{SYS} < 0V$.

Thermal Regulation and Thermal Shutdown

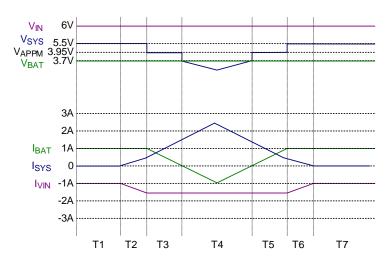
The RT9519E provides a thermal regulation loop function to monitor the device temperature. If the die temperature rises above the regulation temperature, TREG, the charge current will automatically be reduced to lower the die temperature. However, in certain circumstances (such as high VIN, heavy system load, etc.) even with the thermal loop in place, the die temperature may still continue to increase. In this case, if the temperature rises above the thermal shutdown threshold, TsD, the internal switch between VIN and SYS will be turned off. The switch between the battery and SYS will remain on, however, to allow continuous battery power to the load. Once the die temperature decreases by Δ TsD, the internal switch between VIN and SYS will be turned on again and the device returns to normal thermal regulation.

Charging Profile



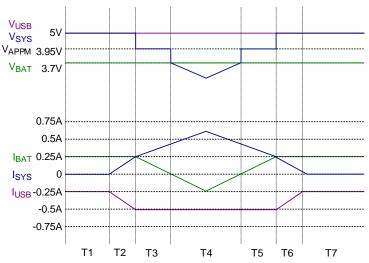
APPM Profile

1.5A Mode :



	Isys	Vsys	Ivin	IBAT
T1, T7	0	SYS Regulation Voltage	CHG_MAX	CHG_MAX
T2, T6	< I _{VIN_OC} - CHG_MAX	SYS Regulation Voltage	Isys + CHG_MAX	CHG_MAX
T3, T5	> Ivin_oc- CHG_MAX < Ivin_oc	Auto Charge Voltage Threshold	VIN_OC	VIN_OC-ISYS
T4	> IVIN_OC	VBAT-IBAT X RDS(ON)	VIN_OC	Isys-Ivin_oc

USB 500mA Mode :



	Isys	Vsys	lusв	Іват
T1, T7	0	0 SYS Regulation Voltage		CHG_MAX
T2, T6	< I _{VIN_OC} (USB)– CHG_MAX	DC (USB)– CHG_MAX SYS Regulation Voltage		CHG_MAX
T3, T5	> Ivin_oc (USB)– CHG_MAX < Ivin_oc (USB)	Auto Charge Voltage Threshold	Ivin_oc (USB)	IVIN_OC (USB)–Isys
T4	> Ivin_oc (USB)	VBAT-IBAT X RDS(ON)	Ivin_oc (USB)	Isys-Ivin_oc (USB)

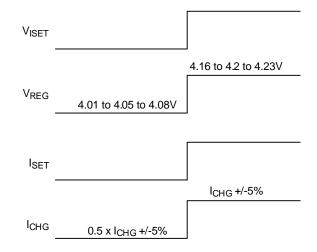
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 DS9519E-03
 February
 2024

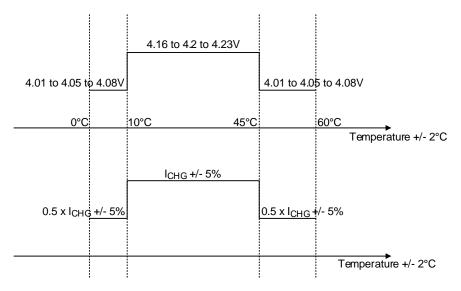
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VSET vs. VREG, ISET vs. ICHG

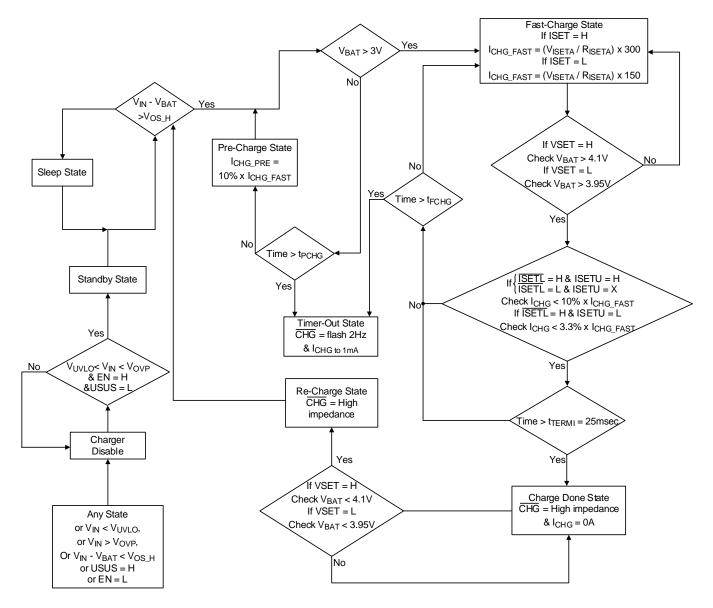


For JEITA Battery Temperature Standard : CV regulation voltage will change at the following battery Temp ranges 0°C to 10°C and 45°C to 60°C CC regulation current will change at the following battery Temp ranges 0°C to 10°C and 45°C to 60°C





RT9519E Operation State Diagram for Charging





Thermal Considerations

The junction temperature should never exceed the absolute maximum junction temperature T_J(MAX), listed under Absolute Maximum Ratings, to avoid permanent damage to the device. The maximum allowable power dissipation depends on the thermal resistance of the IC package, the PCB layout, the rate of surrounding airflow, and the difference between the junction and ambient temperatures. The maximum power dissipation can be calculated using the following formula :

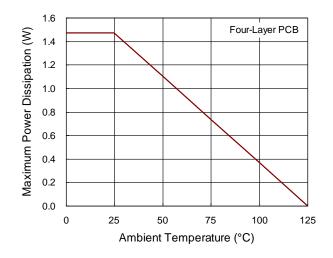
 $\mathsf{PD}(\mathsf{MAX}) = (\mathsf{TJ}(\mathsf{MAX}) - \mathsf{TA}) / \theta \mathsf{JA}$

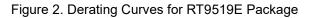
where $T_{J(MAX)}$ is the maximum junction temperature, T_A is the ambient temperature, and θ_{JA} is the junction-toambient thermal resistance.

For continuous operation, the maximum operating junction temperature indicated under Recommended Operating Conditions is 125°C. The junction-to-ambient thermal resistance, θ_{JA} , is highly package dependent. For a WQFN-20L 3x3 package, the thermal resistance, θ_{JA} , is 68°C/W on a standard JEDEC 51-7 high effective-thermal-conductivity four-layer test board. The maximum power dissipation at $T_A = 25^{\circ}$ C can be calculated as below :

 $\mathsf{P}_{\mathsf{D}(\mathsf{MAX})}$ = (125°C - 25°C) / (68°C/W) = 1.471W for a WQFN-20L 3x3 package.

The maximum power dissipation depends on the operating ambient temperature for the fixed $T_{J(MAX)}$ and the thermal resistance, θ_{JA} . The derating curves in Figure 2 allows the designer to see the effect of rising ambient temperature on the maximum power dissipation.





Layout Considerations

The RT9519E is a fully integrated low cost single cell Lilon battery charger ideal for portable applications. Careful PCB layout is necessary. For best performance, place all peripheral components as close to the IC as possible.

A short connection is highly recommended. The following guidelines should be strictly followed when designing a PCB layout for the RT9519E.

For the best performance of the RT9519E, the following PCB layout guidelines must be strictly followed.

- Input and output capacitor should be placed close to IC and connected to ground plane. The trace of input in the PCB should be placed far away from the sensitive devices and shielded by the ground.
- The GND and exposed pad should be connected to a strong ground plane for heat sinking and noise protection.
- The connection of RISETA should be isolated from other noisy traces. A short wire is recommended to prevent EMI and noise coupling.

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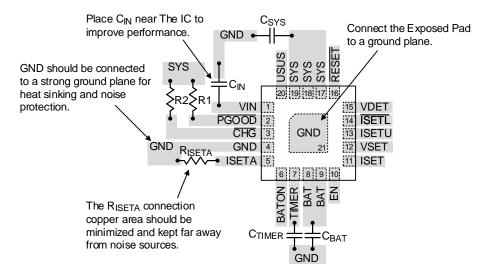
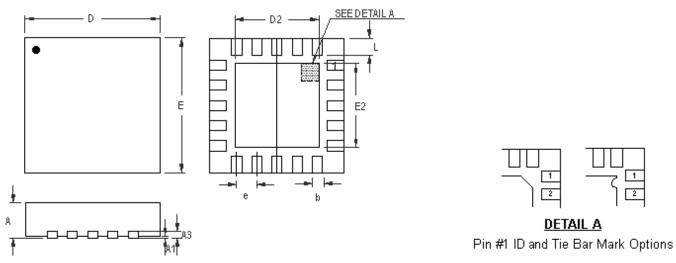


Figure 3. PCB Layout Guide



Outline Dimension



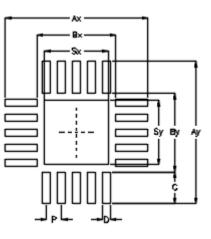
Note : The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions	In Millimeters	Dimensions In Inches			
Symbol	Min	Max	Min	Max		
А	0.700	0.800	0.028	0.031		
A1	0.000	0.050	0.000	0.002		
A3	0.175	0.250	0.007	0.010		
b	0.150	0.250	0.006	0.010		
D	2.900	3.100	0.114	0.122		
D2	1.650	1.750	0.065	0.069		
E	2.900	3.100	0.114	0.122		
E2	1.650	1.750	0.065	0.069		
е	0.4	100	0.016			
L	0.350	0.450	0.014	0.018		

W-Type 20L QFN 3x3 Package



Footprint Information

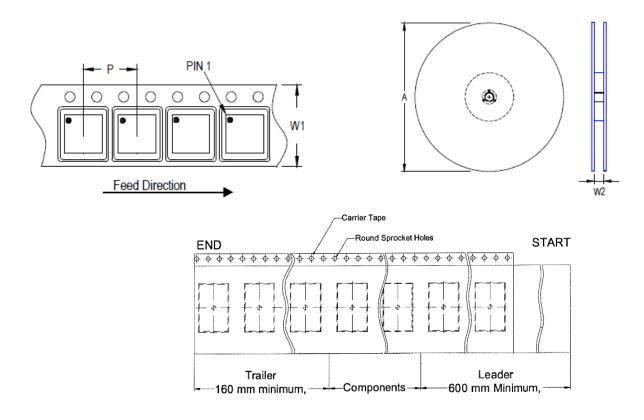


Deekege	Number of		Footprint Dimension (mm)								Toloropoo
Package	Pin	Р	Ax	Ay	Вx	Ву	С	D	Sx	Sy	Tolerance
V/W/U/XQFN3*3-20	20	0.40	3.80	3.80	2.10	2.10	0.85	0.20	1.70	1.70	±0.05

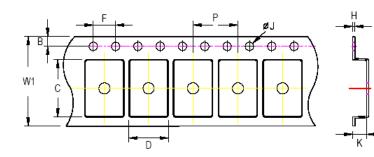


Packing Information

Tape and Reel Data



Deelve se Ture	Tape Size	Pocket Pitch	Reel Si	ze (A)	Units	Trailer	Leader	Reel Width (W2)	
Package Type	(W1) (mm)	(P) (mm)	(mm)	(in)	per Reel	(mm)	(mm)	Min./Max. (mm)	
QFN/DFN 3x3	12	8	180	7	1,500	160	600	12.4/14.4	



C, D, and K are determined by component size. The clearance between the components and the cavity is as follows:

- For 12mm carrier tape: 0.5mm max.

Tana Siza	W1	Р		В		F		ØJ		Н
Tape Size	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Max.
12mm	12.3mm	7.9mm	8.1mm	1.65mm	1.85mm	3.9mm	4.1mm	1.5mm	1.6mm	0.6mm

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Tape and Reel Packing

Step	Photo/Description	Step	Photo/Description
1		4	
	Reel 7"		3 reels per inner box Box A
2		5	
	HIC & Desiccant (1 Unit) inside		12 inner boxes per outer box
3			RICHTEK TRAILIZE BOOD
	Caution label is on backside of Al bag		Outer box Carton A

Container	R	eel	Box			Carton			
Package	Size	Units	Item	Reels	Units	Item	Boxes	Unit	
	7"	7" 1,500	Box A	3	4,500	Carton A	12	54,000	
QFN & DFN 3x3			Box E	1	1,500	For Combined or Partial Reel.			

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Packing Material Anti-ESD Property

Surface Resistance	Aluminum Bag	Reel	Cover tape	Carrier tape	Tube	Protection Band
Ω/cm^2	10 ⁴ to 10 ¹¹					

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Datasheet Revision History

Version	Date	Description	Item
01	2022/11/23	Modify	Electrical Characteristics on P5 Application Information on P10 Footprint Information on P19 Packing Information on P20, 21, 22
02	2023/10/2	Modify	General Description on P1 Ordering Information on P1 Electrical Characteristics on P4, 5 Application Information on P10
03	2024/2/6	Modify	Absolute Maximum Ratings on P4 Packing Information on P21